

TPS60310, TPS60311, TPS60312, TPS60313 SINGLE-CELL TO 3-V/3.3-V, 20-mA DUAL OUTPUT, HIGH-EFFICIENCY CHARGE PUMP WITH SNOOZE MODE

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features

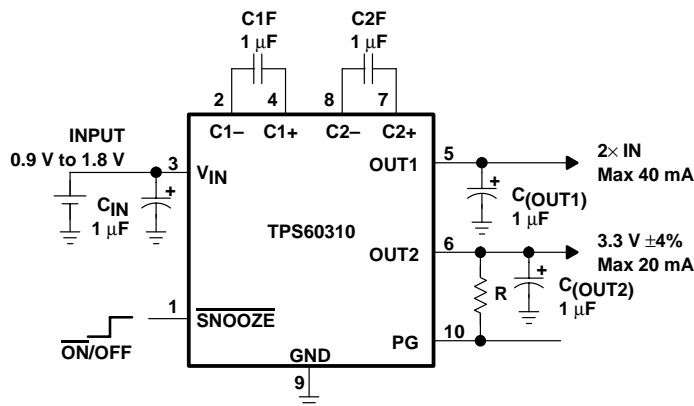
- Regulated 3-V or 3.3-V Output Voltage With up to 20-mA Output Current From a 0.9-V to 1.8-V Input Voltage Range
- High Power Conversion Efficiency (up to 90%) Over Wide Output Current Range, Optimized for 1.2-V Battery Voltage
- Snooze Mode for Improved Efficiency at Low-Output Current
- Additional Output With 2 Times V_I (OUT1)
- Device Quiescent Current Less Than 2 μ A
- Supervisor Included; Open Drain or Push-Pull Power Good Output
- No Inductors Required/Low EMI
- Only Five Small, 1- μ F Ceramic Capacitors Required
- Microsmall 10-Pin MSOP Package

description

The TPS6031X step-up, regulated charge pumps generate a 3-V $\pm 4\%$ or 3.3-V $\pm 4\%$ output voltage from a 0.9-V to 1.8-V input voltage (one alkaline, NiCd, or NiMH battery).

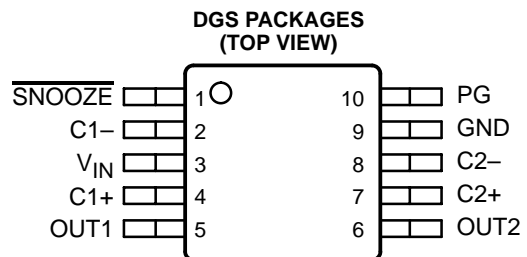
Only five small 1- μ F ceramic capacitors are required to build a complete high-efficiency dc/dc charge pump converter. To achieve the high efficiency over a wide input voltage range, the charge pump automatically selects between a 3x or 4x conversion mode.

typical application circuit

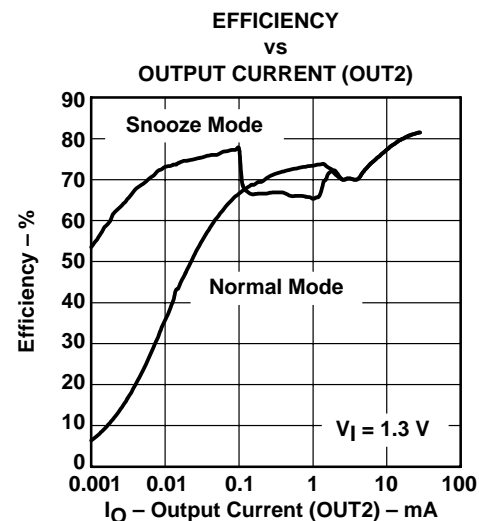


applications

- Pagers
- Battery-Powered Toys
- Portable Measurement Instruments
- Home Automation Products
- Medical Instruments (Like Hearing Instruments)
- Metering Applications Using MSP430 Microcontroller
- Portable Smart Card Readers



ACTUAL SIZE
3,05 mm x 4,98 mm



Snooze mode improves efficiency at an output current in the range of 1 μ A to 100 μ A.



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

**TEXAS
INSTRUMENTS**

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description (continued)

Output 1 (OUT1) can deliver a maximum of 40 mA, from a 1-V input, with output 2 (OUT2) not loaded. OUT2 can deliver a maximum of 20 mA, from a 1-V input, with OUT1 not loaded. Both outputs can be loaded at the same time, but the total output current of the first voltage doubler must not exceed 40 mA. For example, the load at OUT1 is 20 mA and the load at output 2 is 10 mA.

In snooze mode, the devices operate with a typical operating current of 2 μ A, while the output voltage is maintained at 3.3 V \pm 10% or 3 V \pm 10%, respectively. This is lower than the self-discharge current of most batteries. Load current in snooze mode is limited to 2 mA. If the load current increases above 2 mA, the output voltage drops further and the devices automatically exits the snooze mode and operate in normal mode to regulate to the nominal output voltage with higher output currents. The device is set into the snooze mode by taking the SNOOZE pin low, and is set into normal operating mode by taking the SNOOZE pin high.

A power-good function supervises the output voltage of OUT2 and can be used for power up and power down sequencing. Power-good (PG) is offered as either open-drain or push-pull output.

AVAILABLE OPTIONS

PART NUMBER†	MARKING DGS PACKAGE	OUTPUT CURRENT 1 [mA]‡	OUTPUT CURRENT 2 [mA]§	OUTPUT VOLTAGE 1 [V]	OUTPUT VOLTAGE 2 [V]	FEATURE
TPS60310DGS	ATG	40	20	2 x V_{IN}	3.3	Open-drain power-good output
TPS60311DGS	ATI	40	20	2 x V_{IN}	3	Open-drain power-good output
TPS60312DGS	ATK	40	20	2 x V_{IN}	3.3	Push-pull power-good output
TPS60313DGS	ATL	40	20	2 x V_{IN}	3	Push-pull power-good output

† The DGS package is available taped and reeled. Add R suffix to device type (e.g. TPS60310DGSR) to order quantities of 2500 devices per reel.

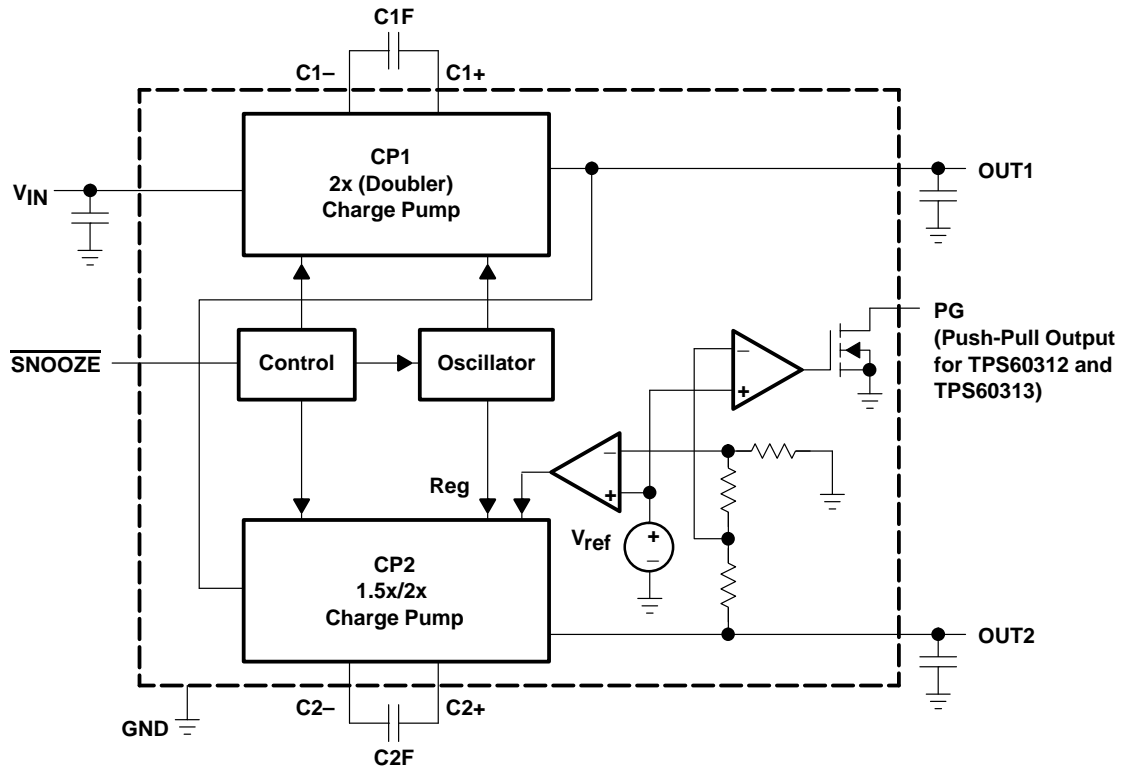
‡ If OUT2 is not loaded.

§ If OUT1 is not loaded.

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TPS60310 and TPS60311 functional block diagram



Terminal Functions

TERMINAL NAME	NO.	I/O	DESCRIPTION
C1+	4		Positive terminal of the flying capacitor C1F
C1–	2		Negative terminal of the flying capacitor C1F
C2+	7		Positive terminal of the flying capacitor C2F
C2–	8		Negative terminal of the flying capacitor C2F
GND	9		GROUND
OUT1	5	O	$2 \times V_{IN}$ power output. Bypass OUT1 to GND with the output filter capacitor $C_{(OUT1)}$.
OUT2	6	O	Regulated 3.3-V power output (TPS60310, TPS60312) or 3-V power output (TPS60311, TPS60313), respectively. Bypass OUT2 to GND with the output filter capacitor $C_{(OUT2)}$.
PG	10	O	Power good detector output. As soon as the voltage on OUT2 reaches about 98% of its nominal value this pin goes high. Open drain output on TPS60310 and TPS60311. A pullup resistor should be connected between PG and OUT1 or OUT2. Push-pull output stage on TPS60312 and TPS60313
SNOOZE	1	I	Snooze mode enable input – SNOOZE = Low enables the snooze mode at low output current. – SNOOZE = High disables the snooze mode.
V _{IN}	3	I	Supply input. Bypass V _{IN} to GND with a $\geq 1\text{-}\mu\text{F}$ capacitor.

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detailed description

operating principle

The TPS6031X charge pumps are voltage quadruplers that provide a regulated 3.3-V or 3-V output from a 0.9-V to 1.8-V input. They deliver a maximum load current of 20 mA. Designed specifically for space critical battery powered applications, the complete converter requires only five external capacitors and enables the design to use low-cost, small-sized, 1- μ F ceramic capacitors. The TPS6031X circuits consist of an oscillator, a voltage reference, an internal resistive feedback circuit, two error amplifiers, two charge pump stages with MOSFET switches, a shutdown/start-up circuit, and a control circuit.

snooze mode

The devices contain a circuit which dramatically reduces the quiescent current at light loads. This so called snooze mode must be enabled by pulling the $\overline{\text{SNOOZE}}$ pin low. When the output current decreases below the snooze mode threshold, the device enters the snooze mode. In snooze mode, the main error amplifier with 4% error and 50- μ A supply current is disabled and a 10%, 2- μ A regulator controls the output voltage.

start-up procedure

The start-up performance of the device is independent of the level of the snooze input. When voltage is applied to the input, CP1 will first enter a dc start-up mode during which the capacitor on OUT1 is charged up to about V_{IN} . After that, it starts switching to boost the voltage further up to about two times V_{IN} . CP1 first enters a dc start-up mode during which the capacitor on OUT1 is charged up to about V_{IN} . CP2 then follows and charges up the capacitor on OUT2 to about the voltage on OUT1, after that, it also starts switching and boosts up the voltage to its nominal value. The voltage at the $\overline{\text{SNOOZE}}$ pin must not exceed the highest voltage applied to the device.

NOTE:

During start-up with $V_{\text{OUT}} = 0$ V, the highest voltage is the input voltage.

power-good detector

The power-good output is an open-drain output on the TPS60310 and TPS60311 or a push-pull output on the TPS60312 and TPS60313. The PG-output pulls low when the output of OUT2 is out of regulation. When the output rises to within 98% of regulation, the power-good output goes active high. In shutdown, power-good is pulled low. In normal operation, an external pullup resistor with the TPS60310 and TPS60311 is typically used to connect the PG pin to VOUT. The resistor should be in the 100-k Ω to 1-M Ω range. If the PG output is not used, it should remain unconnected. Output current at PG (TPS60312, TPS60313) reduces maximum output current at OUT2.

In snooze mode, the output voltage is sampled at a rate up to 2 ms and is applied to the power-good comparator. In normal mode, the output voltage is measured continuously.

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absolute maximum ratings over operating free-air temperature (unless otherwise noted)[†]

Input voltage, V_I (IN to GND) (see Note 1)	–0.3 V to 2 V
Output voltage, V_O (OUT1, OUT2, EN, PG to GND) (see Note 1)	–0.3 V to 3.6 V
Voltage, (C1+ to GND)	–0.3 V to $V_{O(OUT1)} + 0.3$ V
Voltage, (C1– to GND, C2– to GND)	–0.3 V to $V_{IN} + 0.3$ V
Voltage, (C2+ to GND)	–0.3 V to $V_{O(OUT2)} + 0.3$ V
Continuous power dissipation	See Dissipation Rating Table
Output current, I_O (OUT1)	80 mA
Output current, I_O (OUT2)	40 mA
Storage temperature range, T_{stg}	–55°C to 150°C
Maximum junction temperature, T_J	150°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The voltage at SNOOZE and PG can exceed IN up to the maximum rated voltage without increasing the leakage current drawn by these pins.

DISSIPATION RATING TABLE

PACKAGE	$T_A < 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING
DGS	424 mW	3.4 mW/°C	271 mW	220 mW

NOTE: The thermal resistance junction to ambient of the DGS package is $R_{TH-JA} = 294^\circ\text{C/W}$.

recommended operating conditions

	MIN	NOM	MAX	UNIT
Input voltage, V_I	0.9		1.8	V
Output current (OUT2), $I_{O(OUT2)}$			20	mA
Output current (OUT1), $I_{O(OUT1)}$			40	mA
Input capacitor, C_I	1			μF
Flying capacitors, C1F, C2F		1		μF
Output capacitors, $C_{O(1)}$, $C_{O(2)}$	1			μF
Operating junction temperature, T_J	–40		125	°C

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electrical characteristics at $C_{IN} = C1F = C2F = C_{(OUT1)} = C_{(OUT2)} = 1 \mu F$, $T_C = -40^\circ C$ to $85^\circ C$, $V_{IN} = 1 V$, $V_{(SNOOZE)} = V_{IN}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{IN}	Supply voltage range		0.9		1.8	V
$I_{O(OUT1)}$	Maximum output current for TPS60310, TPS60312	$V_{IN} \geq 1.1 V$, $I_{O(OUT2)} = 0 mA$, $I_{(PG,1)} = 0 mA$	40			mA
		$V_{IN} = 0.9 V$, $I_{O(OUT2)} = 0 mA$, $I_{(PG,1)} = 0 mA$	20			
$I_{O(OUT2)}$		$V_{IN} \geq 1.1 V$, $I_{O(OUT1)} = 0 mA$, $I_{(PG,1)} = 0 mA$	20			
		$V_{IN} = 0.9 V$, $I_{O(OUT1)} = 0 mA$, $I_{(PG,1)} = 0 mA$	10			
$I_{O(OUT1)}$	Maximum output current for TPS60311, TPS60313	$V_{IN} \geq 1.1 V$, $I_{O(OUT2)} = 0 mA$, $I_{(PG,1)} = 0 mA$	40			mA
		$V_{IN} = 0.9 V$, $I_{O(OUT2)} = 0 mA$, $I_{(PG,1)} = 0 mA$	20			
$I_{O(OUT2)}$		$V_{IN} \geq 1 V$, $I_{O(OUT1)} = 0 mA$, $I_{(PG,1)} = 0 mA$	20			
		$V_{IN} = 0.9 V$, $I_{O(OUT1)} = 0 mA$, $I_{(PG,1)} = 0 mA$	12			
$V_{O(OUT2)}$	Output voltage for TPS60310, TPS60312	$1.1 V < V_{IN} < 1.8 V$, $I_{O(OUT1)} = 0 mA$ $0 < I_{O(OUT2)} < 20 mA$	3.17	3.3	3.43	V
		$0.9 V < V_{IN} < 1.1 V$, $I_{O(OUT1)} = 0 mA$, $I_{O(OUT2)} < 10 mA$	3.17	3.3	3.43	V
		$0.9 V < V_{IN} < 1.8 V$, $V_{(SNOOZE)} = 0 V$, $0 < I_{O(OUT2)} < 1 mA$ or $0 < I_{O(OUT1)} < 2 mA$	2.85	3.3	3.6	V
$V_{O(OUT2)}$	Output voltage for TPS60311, TPS60313	$1 V < V_{IN} < 1.8 V$, $I_{O(OUT1)} = 0 mA$, $0 < I_{O(OUT2)} < 20 mA$	2.88	3	3.12	V
		$V_{IN} > 1.65 V$, $I_{O(OUT1)} = 0 mA$, $25 \mu A < I_{O(OUT2)} < 20 mA$	2.88	3	3.15	V
		$0.9 V < V_{IN} < 1.8 V$, $V_{(SNOOZE)} = 0 V$, $0 < I_{O(OUT2)} < 1 mA$ or $0 < I_{O(OUT1)} < 2 mA$	2.6	3.3	3.27	V
V_{P-P}	Output voltage ripple	OUT2 $I_{O(OUT2)} = 20 mA$, $I_{O(OUT1)} = 0 mA$		30		mV _{P-P}
		OUT1 $I_{O(OUT1)} = 40 mA$, $I_{O(OUT2)} = 0 mA$		60		
I_Q	Quiescent current (no-load input current)	$I_O = 0 mA$, $V_{IN} = 1.8 V$		35	70	μA
$I_{(SQ)}$	Quiescent supply current in snooze mode	$V_{IN} = 1.65 V$, $V_{(SNOOZE)} = 0 V$, $T_C = 60^\circ C$		2	10	μA
		$V_{IN} = 1.65 V$, $V_{(SNOOZE)} = 0 V$, $T_C \leq 25^\circ C$		1.5	4	
f_{OSC}	Internal switching frequency		470	700	900	kHz
$V_{IL(EN)}$	EN input low voltage	$V_{IN} = 0.9 V$ to $1.8 V$			$0.3 \times V_{IN}$	V
$V_{IH(EN)}$	EN input high voltage	$V_{IN} = 0.9 V$ to $1.8 V$	$0.7 \times V_{IN}$			V
I_{lkg}	EN input leakage current	$V_{(EN)} = 0 V$ or V_{IN} or $V_{O(OUT2)}$ or $V_{O(OUT1)}$		0.01	0.1	μA
	LinSkip switching threshold	$V_{IN} = 1.25 V$		7.5		mA
	Snooze mode threshold	$V_{IN} = 1.25 V$	$I_{O(OUT1)}$	2	8	mA
			$I_{O(OUT2)}$	1	4	mA



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electrical characteristics at $C_{IN} = C1F = C2F = C_{(OUT1)} = C_{(OUT2)} = 1\ \mu F$, $T_C = -40^\circ C$ to $85^\circ C$, $V_{IN} = 1\ V$, $V_{(SNOOZE)} = V_{IN}$ (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
Short circuit current	V _{IN} = 1.8 V	V _O (OUT2) = 0 V	5	20	50	mA
		V _O (OUT1) = 0 V	2	80	150	
Output load regulation	V _{IN} = 1.25 V, T _C = 25°C 2 mA < I _O (OUT2) < 20 mA		0.1			%/mA
Output line regulation	1 V < V _{IN} < 1.65 V, T _C = 25°C, I _O (OUT) = 10 mA		0.75			%/V
	1 V < V _{IN} < 1.65 V, T _C = 25°C, I _O (OUT2) = 1 mA, V(SNOOZE) = 0 V		1			%/V
No load start-up time			400			μs
Impedance of first charge pump stage			4.0			Ω
Start-up performance at OUT2 (minimum start-up load resistance)	V _{IN} ≥ 1.1 V		165			Ω
	V _{IN} ≥ 1 V		330			
	V _{IN} = 0.9 V		1000			
Startup performance at OUT1 (minimum start-up load resistance)	V _{IN} = 1 V		500			Ω

electrical characteristics for power good comparator of devices TPS6031X at $T_C = -40^\circ C$ to $85^\circ C$, $V_{IN} = 1\ V$ and $V_{(SNOOZE)} = V_{IN}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{(PG)}$ Power-good trip voltage	V_O ramping positive		$V_O - 1\%$	V_O	V
V_{hys} Power-good trip voltage hysteresis	V_O ramping negative		10%		
V_{OL} Power-good output voltage low	$V_O = 0\ V$, $I_{(PG)} = 1.6\ mA$			0.3	V
I_{lkg} Power-good leakage current	TPS60310	$V_O = 3.3\ V$, $V_{(PG)} = 3.3\ V$	0.01	0.1	μA
	TPS60311	$V_O = 3\ V$, $V_{(PG)} = 3\ V$	0.01	0.1	
V_{OH} Power-good output voltage high	TPS60312	$I_{O(PG)} = -5\ mA$	3		V
	TPS60313		2.7		
$I_{O(PG,1)}$ Output current at power good (source)	TPS60312, TPS60313		-5		mA
$I_{O(PG,0)}$ Output current at power good (sink)	All devices	$V_{(PG)} = 0\ V$	1.6		mA
$R_{(PG,1)}$	Output resistance at power good	TPS60312, TPS60313	$V_{(PG)} = V_{O(OUT2)}$	15	Ω
$R_{(PG,0)}$		All devices	$V_{(PG)} = 0\ V$	100	Ω

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TYPICAL CHARACTERISTICS

Table of Graphs

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TYPICAL CHARACTERISTICS

TPS60310, TPS60312
EFFICIENCY
vs
OUTPUT CURRENT

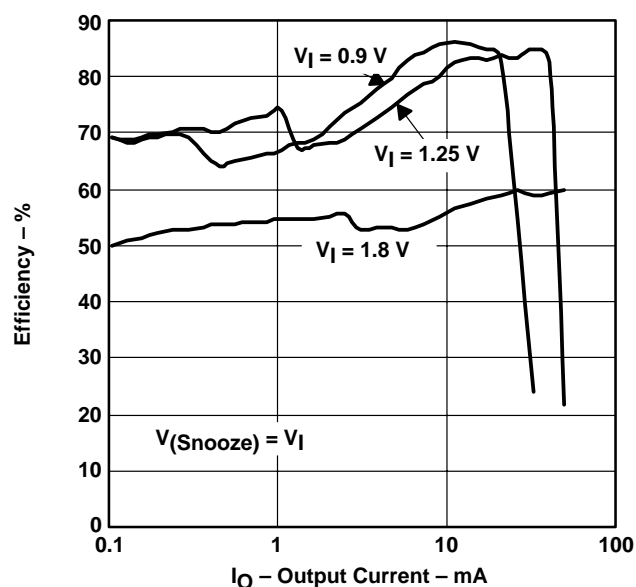


Figure 1

TPS60311, TPS60313
EFFICIENCY
vs
OUTPUT CURRENT

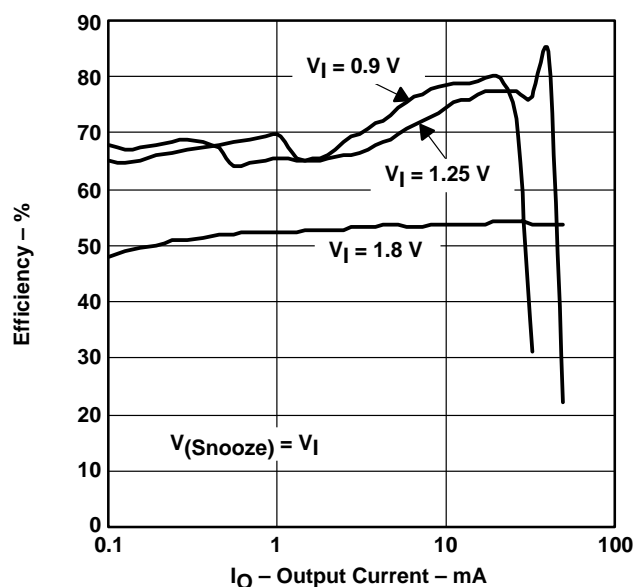
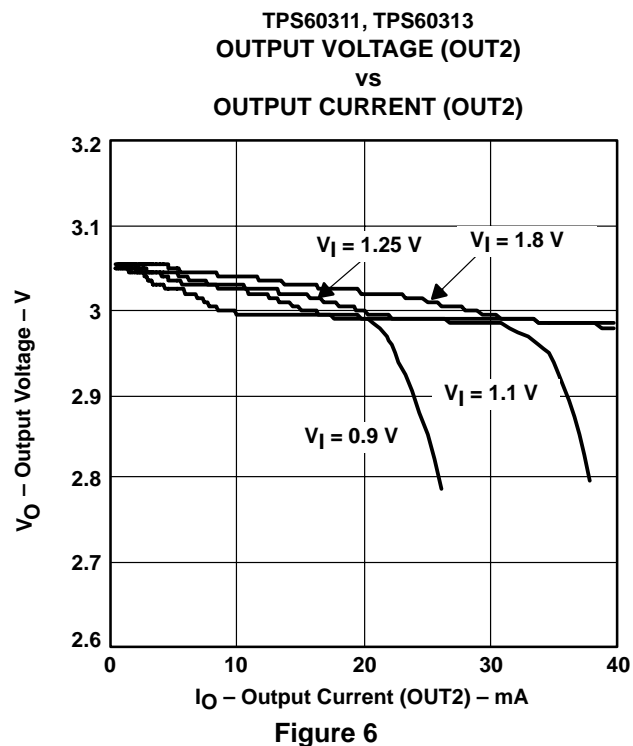
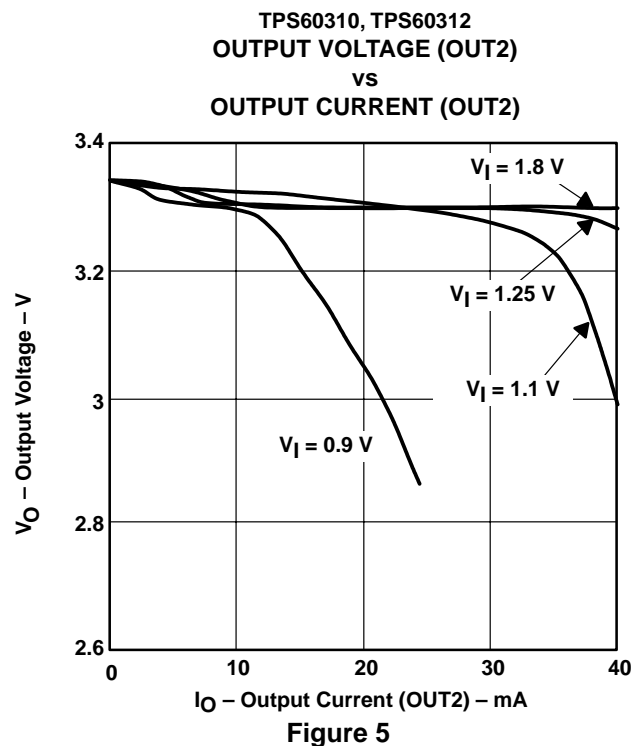
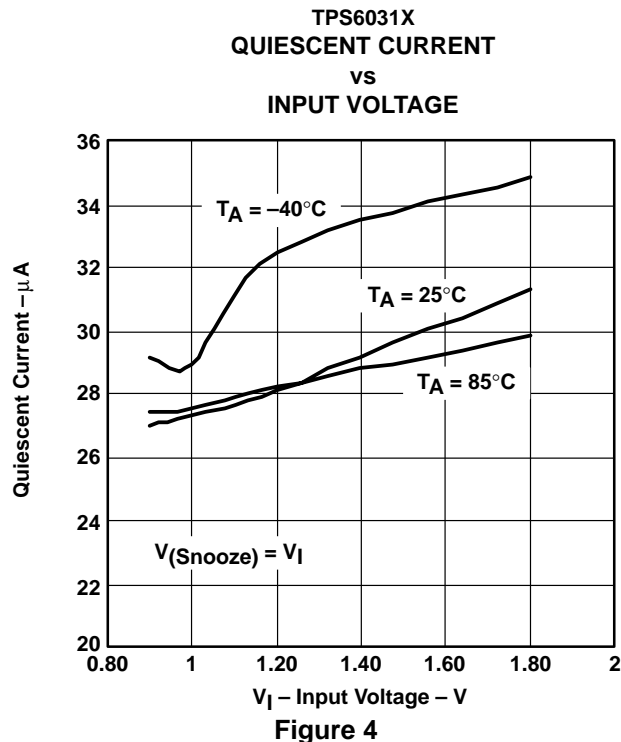
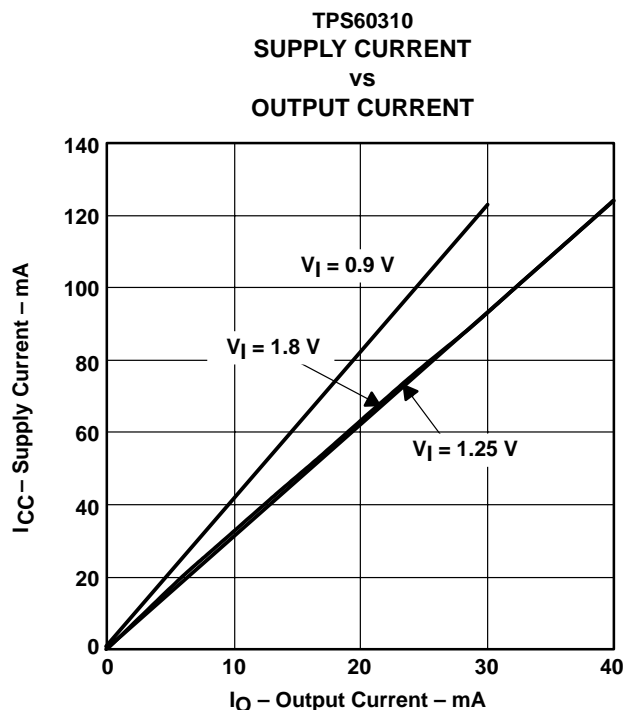


Figure 2

TPS60310, TPS60311, TPS60312, TPS60313
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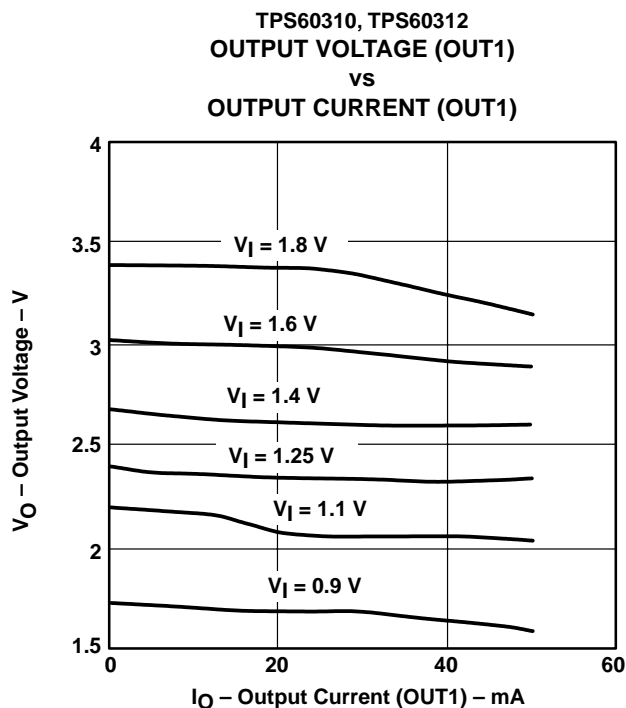


Figure 7

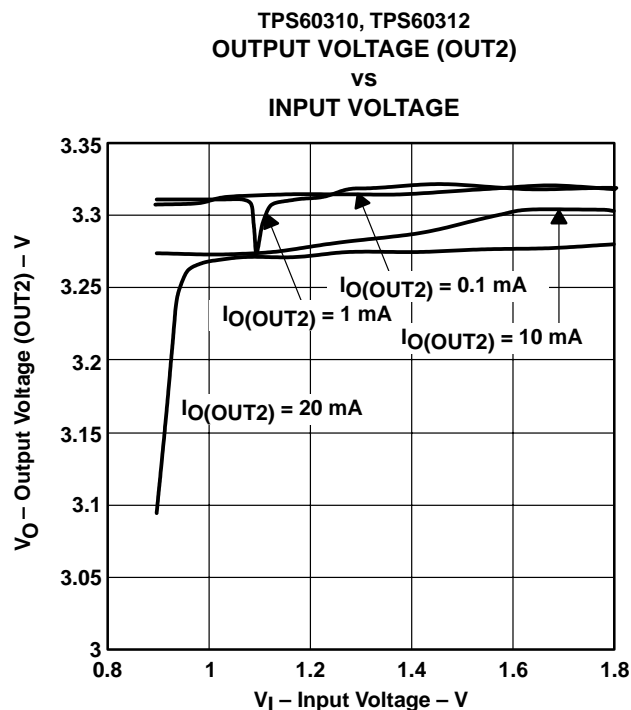


Figure 8

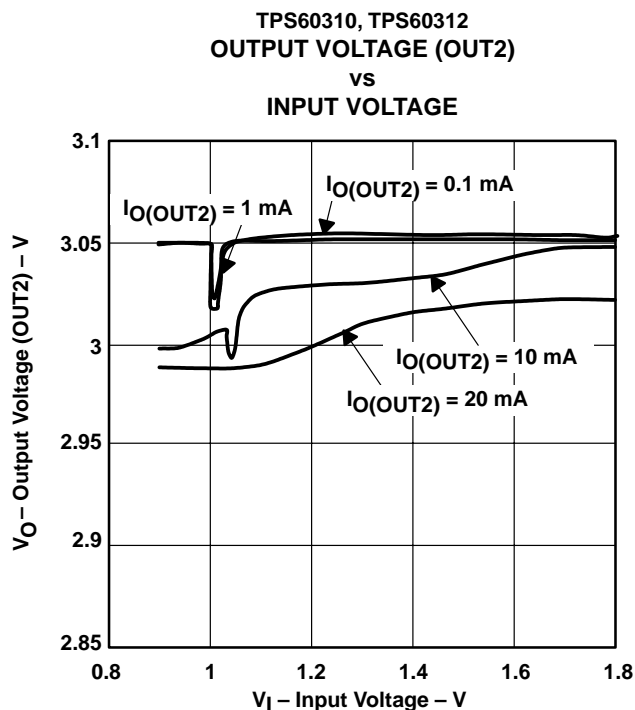


Figure 9

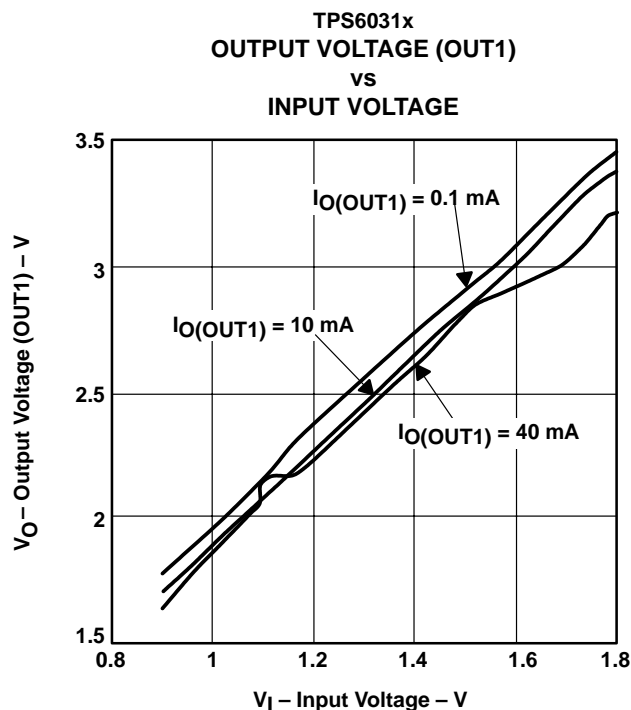


Figure 10

TPS60310, TPS60311, TPS60312, TPS60313
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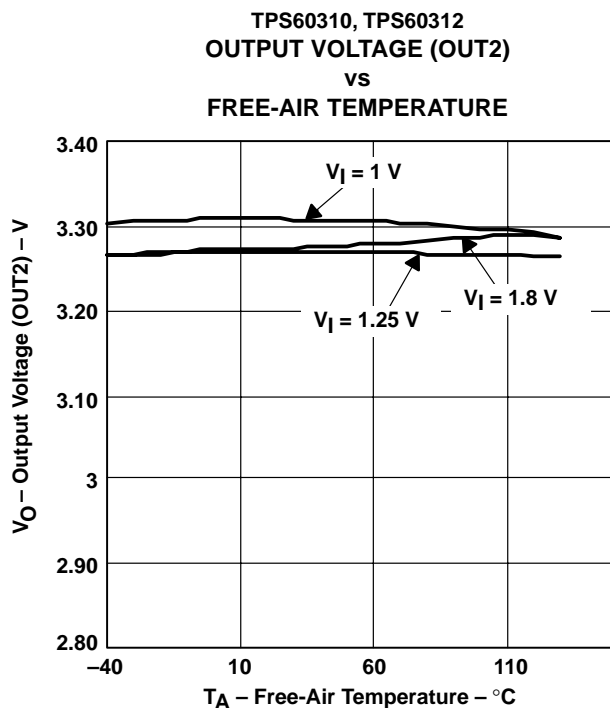


Figure 11

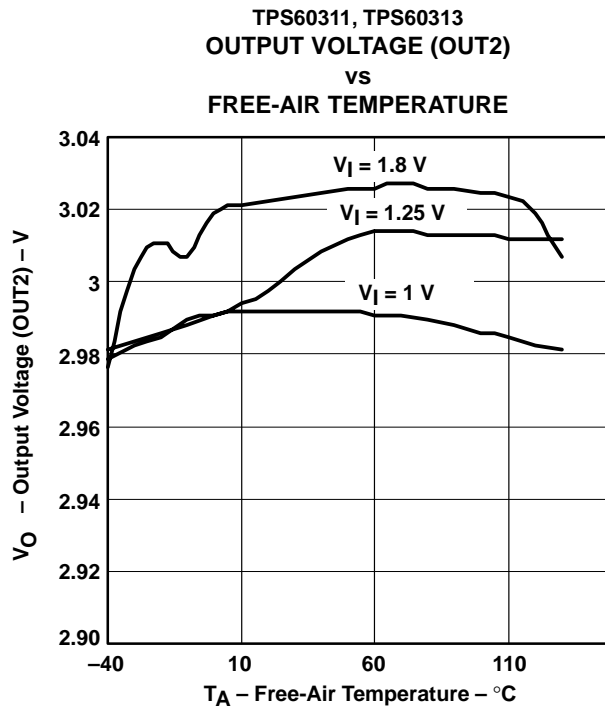


Figure 12

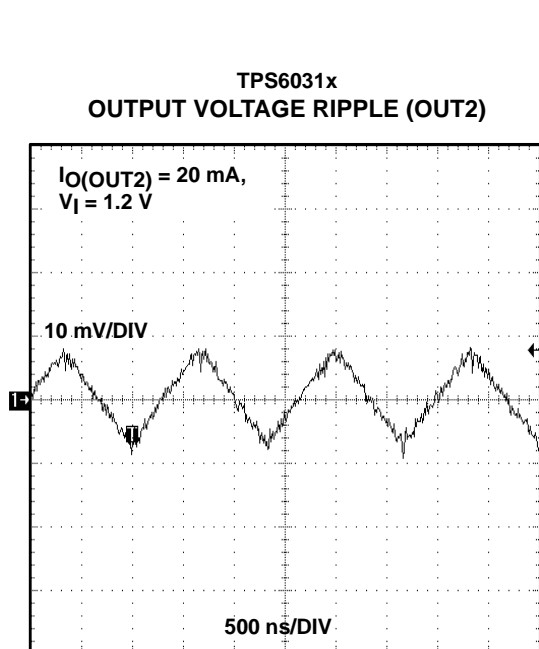


Figure 13

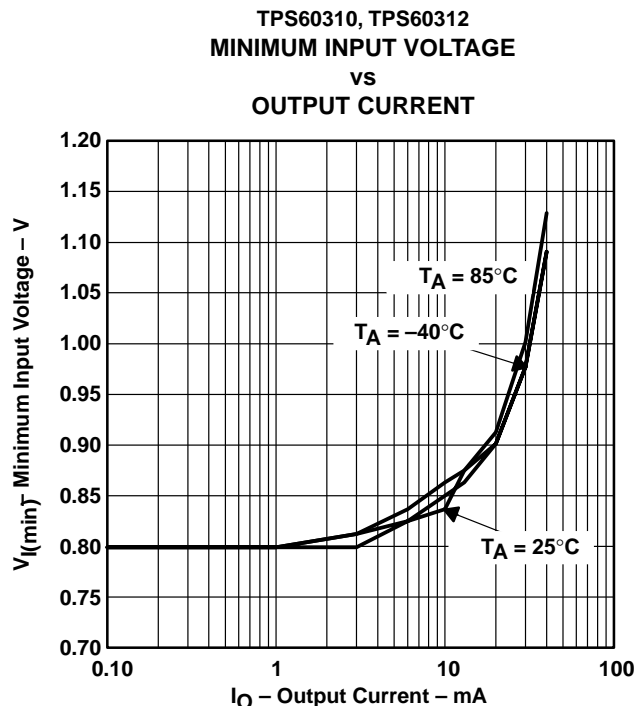


Figure 14

TPS60310, TPS60311, TPS60312, TPS60313
SINGLE-CELL TO 3-V/3.3-V, 20-mA DUAL OUTPUT,
HIGH-EFFICIENCY CHARGE PUMP WITH SNOOZE MODE

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TYPICAL CHARACTERISTICS

TPS60311, TPS60313
MINIMUM INPUT VOLTAGE
vs
OUTPUT CURRENT

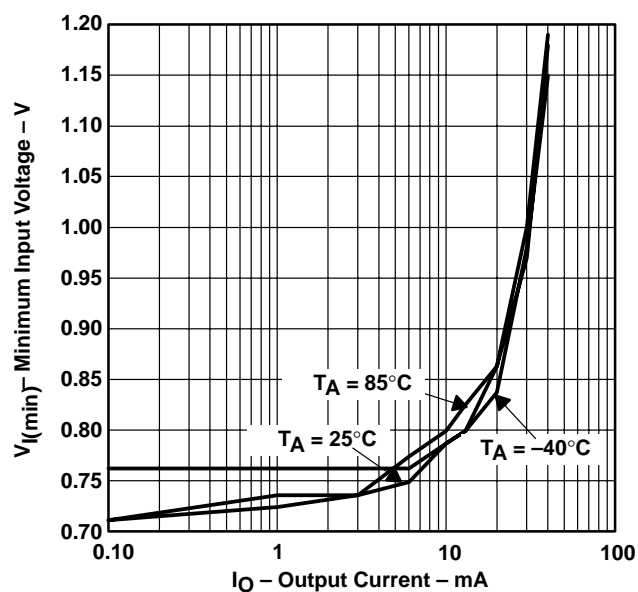


Figure 15

START-UP TIMING ENABLE

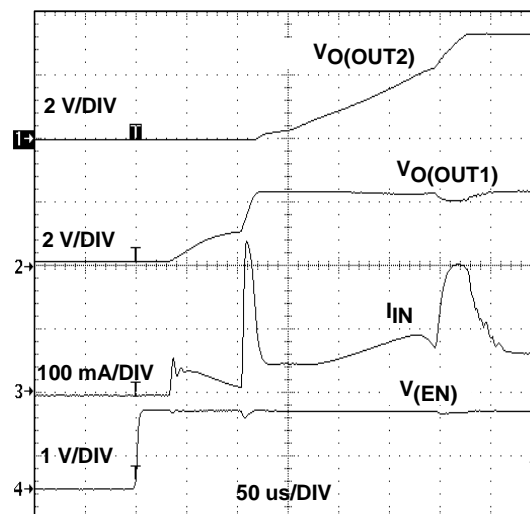


Figure 16

SWITCHING FREQUENCY
vs
INPUT VOLTAGE

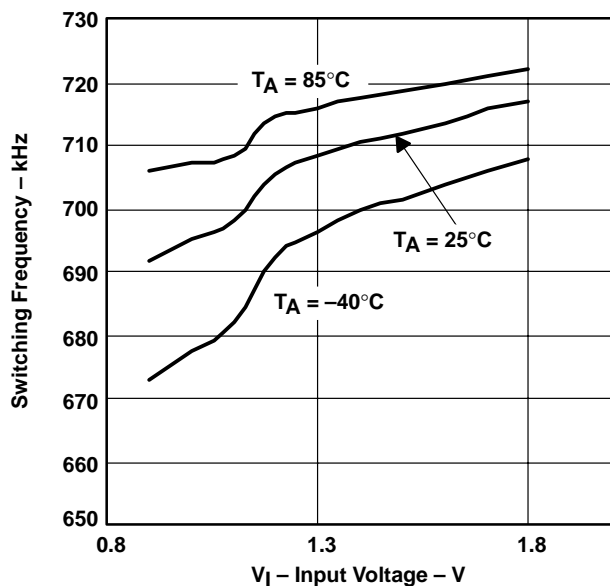


Figure 17

LOAD TRANSIENT RESPONSE

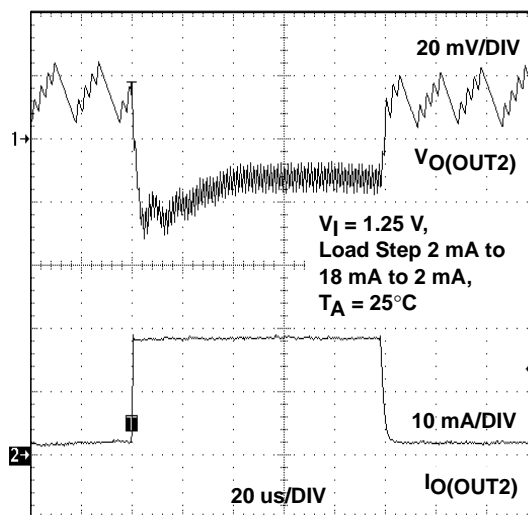


Figure 18

TYPICAL CHARACTERISTICS

LINE TRANSIENT RESPONSE

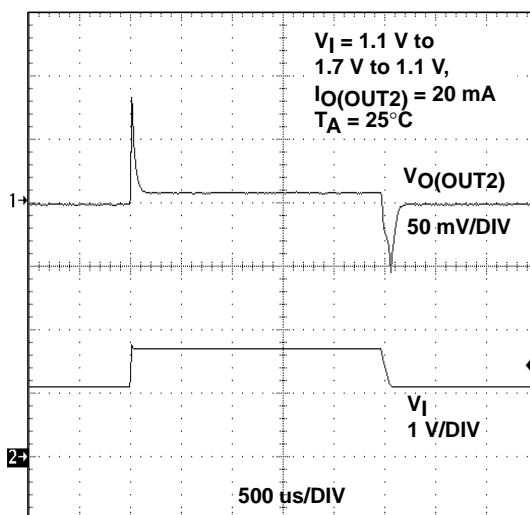


Figure 19

OUTPUT VOLTAGE vs TIME

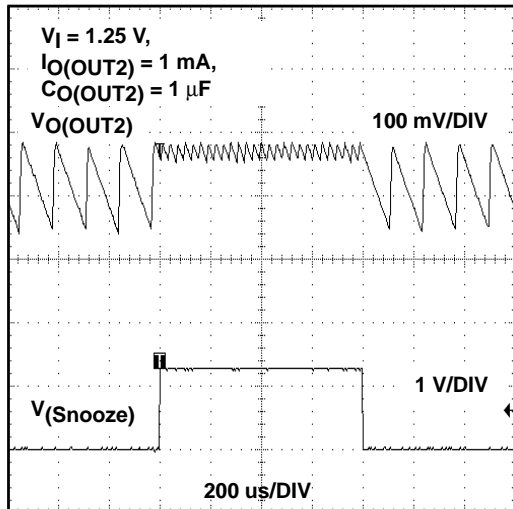


Figure 20

OUTPUT VOLTAGE RIPPLE IN SNOOZE MODE

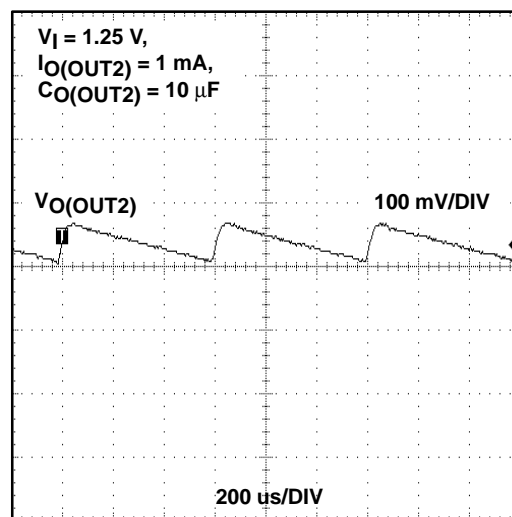


Figure 21

TPS60310, TPS60311, TPS60312, TPS60313
SINGLE-CELL TO 3-V/3.3-V, 20-mA DUAL OUTPUT,
HIGH-EFFICIENCY CHARGE PUMP WITH SNOOZE MODE

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APPLICATION INFORMATION

design procedure

capacitor selection

The TPS6031X devices require only five external capacitors. Their values are closely linked to the required output current and the output noise and ripple requirements. It is possible to only use 1- μ F capacitors of the same type.

The input capacitor improves system efficiency by reducing the input impedance and stabilizing the input current.

The minimum required capacitance of the output capacitor (C_O) that can be selected is 1 μ F. Depending on the maximum allowed output ripple voltage, larger values can be chosen. Table 1 shows capacitor values recommended for low output voltage ripple operation. A recommendation is given for the smallest size.

Table 1. Recommended Capacitor Values for Low-Output Voltage Ripple Operation

V_{IN} [V]	$I_{O(OUT2)}$ [mA]	C_{IN} [μ F]	C_{XF} [μ F]	C_{OUT} [μ F]	V_{P-P} [mV] AT 20 mA/ $V_{IN} = 1.1$ V
		CERAMIC	CERAMIC	CERAMIC	
0.9...1.8	0...20	1	1	1	16
0.9...1.8	0...20	1	1	2.2	10
0.9...1.8	0...20	1	1	10 // 0.1	6

Table 2. Recommended Capacitors

MANUFACTURER	PART NUMBER	SIZE	CAPACITANCE	TYPE
Taiyo Yuden	UMK212BJ104MG	0805	0.1 μ F	Ceramic
	LMK212BJ105KG	0805	1 μ F	Ceramic
	LMK212BJ225MG	0805	2.2 μ F	Ceramic
	JMK316BJ475KL	1206	4.7 μ F	Ceramic
AVX	0805ZC105KAT2A	0805	1 μ F	Ceramic
	1206ZC225KAT2A	1206	2.2 μ F	Ceramic

Table 3 lists the manufacturers of recommended capacitors. However, ceramic capacitors will provide the lowest output voltage ripple due to their typically lower ESR.

Table 3. Recommended Capacitor Manufacturers

MANUFACTURER	CAPACITOR TYPE	INTERNET
Taiyo Yuden	X7R/X5R ceramic	www.t-yuden.com
AVX	X7R/X5R ceramic	www.avxcorp.com
Vishay	X7R/X5R ceramic	www.vishay.com
Kemet	X7R/X5R ceramic	www.kemet.com
TDK	X7R/X5R ceramic	www.component.tdk.com

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TPS60310, TPS60311, TPS60312, TPS60313

SINGLE-CELL TO 3-V/3.3-V, 20-mA DUAL OUTPUT, HIGH-EFFICIENCY CHARGE PUMP WITH SNOOZE MODE

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APPLICATION INFORMATION

output filter design (continued)

Due to $R_{(PG,1)}$, an output filter can easily be formed with an output capacitor (C_{PG}). Cutoff frequency is given by:

$$f_c = \frac{1}{2\pi R_{(PG,1)} C_{PG}} \quad (1)$$

and ratio V_O/V_I for the ac ripple is:

$$\left| \frac{V_{(PG,1)}}{V_{O(OUT2)}} \right| = \frac{1}{\sqrt{1 + \left(2\pi f R_{(PG,1)} C_{PG} \right)^2}} \quad (2)$$

with $R_{(PG,1)} = 15 \, \Omega$, $C_{PG} = 0.1 \, \mu\text{F}$, and $f = 600 \, \text{kHz}$ (at nominal switching frequency)

$$\left| \frac{V_{(PG,1)}}{V_{O(OUT2)}} \right| = 0.175 \quad (3)$$

Load current sourced by power-good output reduces maximum output current at OUT2. During start-up (power-good going high) current charging C_{PG} discharges $C_{(OUT2)}$. Therefore, C_{PG} must not be larger than $C_{PG} \leq 0.1 C_{(OUT2)}$ or the device does not start. By charging C_{PG} through $C_{(OUT2)}$, the output voltage at OUT2 decreases. If the capacitance of C_{PG} is too large, the circuit detects power bad. The power-good output goes low and discharges C_{PG} . Then the cycle starts again. Figure 24 shows a configuration with an LC-post filter to further reduce output ripple and noise.

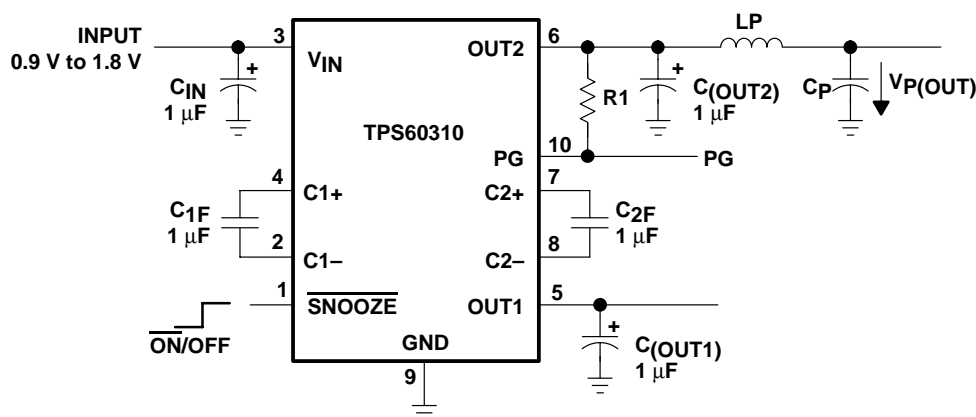


Figure 24. LC-Post Filter

Table 4. Recommended Values for Lowest Output Voltage Ripple

V_{IN} [V]	$I_{O(OUT2)}$ [mA]	$C_{IN}[\mu\text{F}]$ CERAMIC	$C_{XF}[\mu\text{F}]$ CERAMIC	$C_{OUT}[\mu\text{F}]$ CERAMIC	$L_P[\mu\text{H}]$	$C_P[\mu\text{F}]$ CERAMIC	$V_{P(OUT)}$ $V_{P-P}[\text{mV}]$
0.9...1.8	20	1	1	1	0.1	0.1 (X7R)	16
0.9...1.8	20	1	1	1	0.1	1 // 0.1 (X7R)	12
0.9...1.8	20	1	1	1	1	0.1 (X7R)	14
0.9...1.8	20	1	1	1	1	1 // 0.1 (X7R)	3

APPLICATION INFORMATION

output filter design (continued)

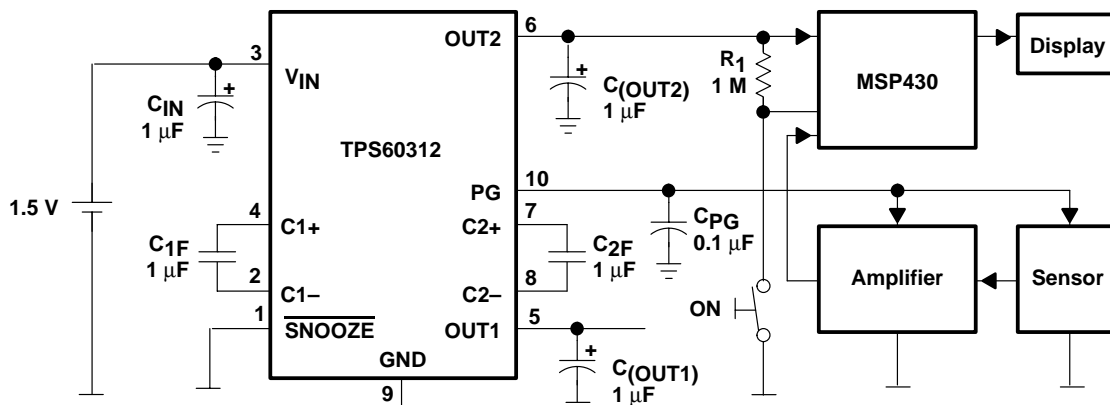


Figure 25. Application With MSP430; PG as Supply for Analog Circuits

power dissipation

As given in the data sheet, the thermal resistance of the unsoldered package is $R_{\theta JA} = 294^{\circ}\text{C/W}$. Soldered on the EVM, a typical thermal resistance of $R_{\theta JA(\text{EVM})} = 200^{\circ}\text{C/W}$ was measured.

The thermal resistance can be calculated using equation 4.

$$R_{\theta JA} = \frac{T_J - T_A}{P_D} \quad (4)$$

Where:

T_J is the junction temperature.

T_A is the ambient temperature.

P_D is the power that needs to be dissipated by the device.

The maximum power dissipation can be calculated using equation 5.

$$P_D = V_{IN} \times I_{IN} - V_O \times I_O = V_{IN(\text{max})} \times (3 \times I_O + I_{(\text{SUPPLY})}) - V_O \times I_O \quad (5)$$

The maximum power dissipation happens with maximum input voltage and maximum output current:

At maximum load the supply current is approximately 2 mA.

$$P_D = 1.8 \text{ V} \times (3 \times 20 \text{ mA} + 2 \text{ mA}) - 3.3 \text{ V} \times 20 \text{ mA} = 46 \text{ mW} \quad (6)$$

With this maximum rating and the thermal resistance of the device on the EVM, the maximum temperature rise above ambient temperature can be calculated using equation 7.

$$\Delta T_J = R_{\theta JA} \times P_D = 200^{\circ}\text{C/W} \times 46 \text{ mW} = 10^{\circ}\text{C} \quad (7)$$

This means that internal dissipation increases T_J by 10°C .

The junction temperature of the device must not exceed 125°C .

This means the IC can easily be used at ambient temperatures up to:

$$T_A = T_{J(\text{max})} - \Delta T_J = 125^{\circ}\text{C} - 10^{\circ}\text{C} = 115^{\circ}\text{C} \quad (8)$$

layout and board space

All capacitors should be soldered as close as possible to the IC. A PCB layout proposal for a two-layer board is shown in Figure 26. Care has been taken to connect all capacitors as close as possible to the circuit to achieve optimized output voltage ripple performance. The bottom layer is not shown in Figure 26. It only consists of a ground-plane with a single track between the two vias that can be seen in the left part of the top layer.

TPS60310, TPS60311, TPS60312, TPS60313
SINGLE-CELL TO 3-V/3.3-V, 20-mA DUAL OUTPUT,
HIGH-EFFICIENCY CHARGE PUMP WITH SNOOZE MODE

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APPLICATION INFORMATION

layout and board space (continued)

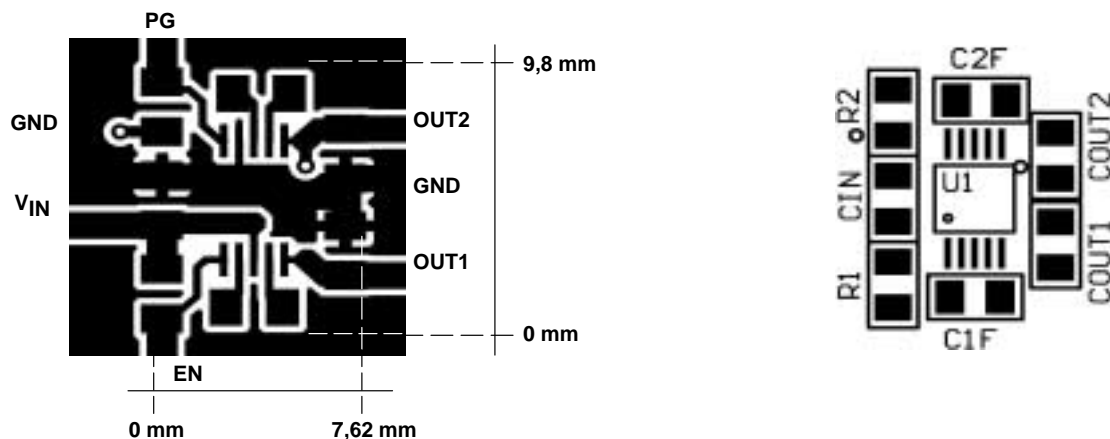


Figure 26. Recommended PCB Layout for TPS6031X (top layer)

device family products

Other charge pump dc-dc converters in this family are:

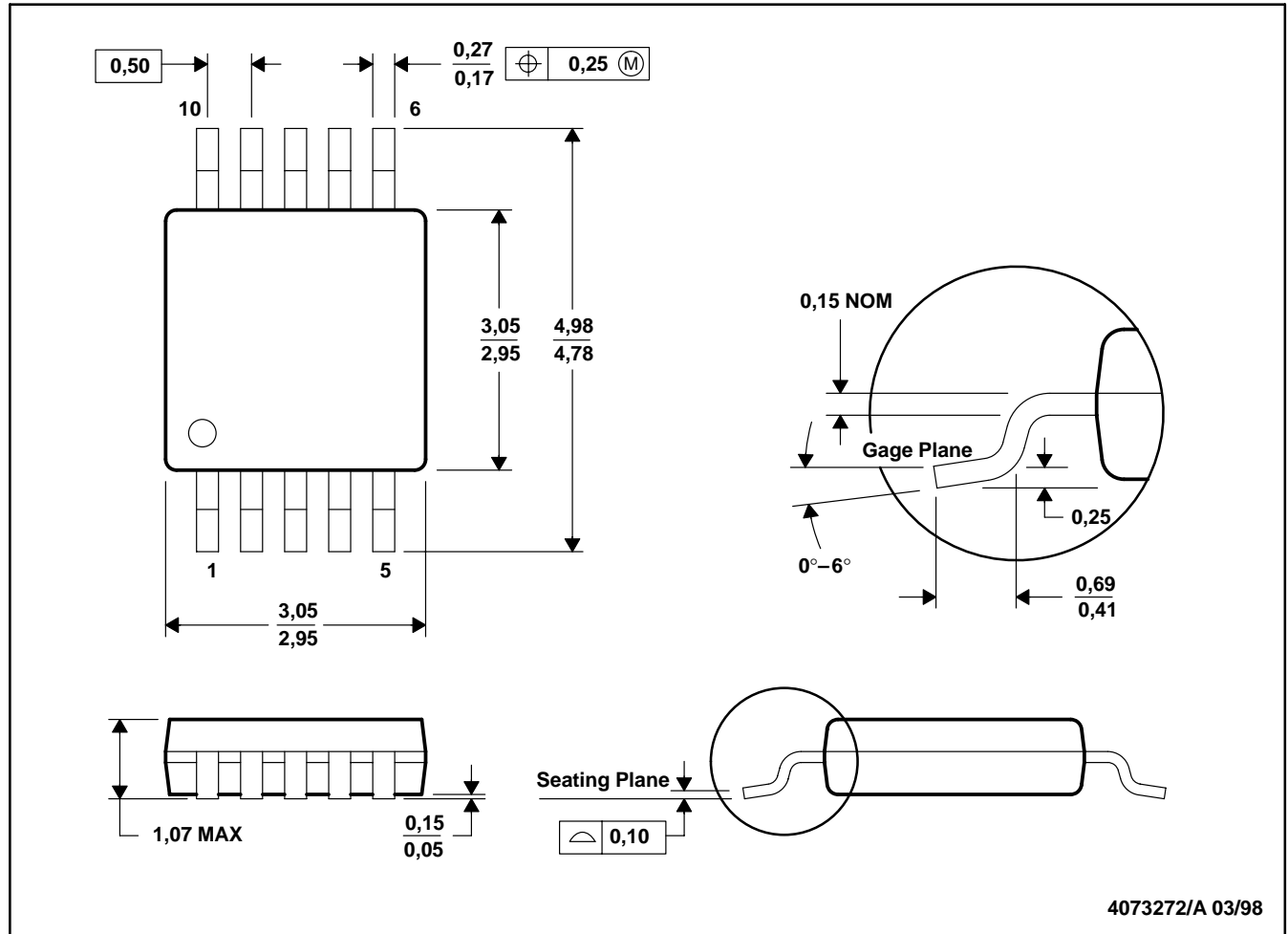
Table 5. Product Identification

PART NUMBER	DESCRIPTION
TPS60100	2-cell to regulated 3.3-V, 200-mA low-noise charge pump
TPS60101	2-cell to regulated 3.3-V, 100-mA low-noise charge pump
TPS60110	3-cell to regulated 5-V, 300-mA low-noise charge pump
TPS60111	3-cell to regulated 5-V, 150-mA low-noise charge pump
TPS60120	2-cell to regulated 3.3-V, 200-mA high-efficiency charge pump with low-battery comparator
TPS60121	2-cell to regulated 3.3-V, 200-mA high-efficiency charge pump with power-good comparator
TPS60122	2-cell to regulated 3.3-V, 100-mA high-efficiency charge pump with low-battery comparator
TPS60123	2-cell to regulated 3.3-V, 100-mA high-efficiency charge pump with power-good comparator
TPS60124	2-cell to regulated 3-V, 200-mA high-efficiency charge pump with low-battery comparator
TPS60125	2-cell to regulated 3-V, 200-mA high-efficiency charge pump with power-good comparator
TPS60130	3-cell to regulated 5-V, 300-mA high-efficiency charge pump with low-battery comparator
TPS60131	3-cell to regulated 5-V, 300-mA high-efficiency charge pump with power-good comparator
TPS60132	3-cell to regulated 5-V, 150-mA high-efficiency charge pump with low-battery comparator
TPS60133	3-cell to regulated 5-V, 150-mA high-efficiency charge pump with power-good comparator
TPS60140	2-cell to regulated 5-V, 100-mA charge pump voltage tripler with low-battery comparator
TPS60141	2-cell to regulated 5-V, 100-mA charge pump voltage tripler with power-good comparator
TPS60200	2-cell to regulated 3.3-V, 100-mA low-ripple charge pump with low-battery comparator in MSOP10
TPS60201	2-cell to regulated 3.3-V, 100-mA low-ripple charge pump with power-good comparator in MSOP10
TPS60202	2-cell to regulated 3.3-V, 50-mA low-ripple charge pump with low-battery comparator in MSOP10
TPS60203	2-cell to regulated 3.3-V, 50-mA low-ripple charge pump with power-good comparator in MSOP10
TPS60210	2-cell to regulated 3.3-V, 100-mA low-ripple charge pump with ultralow operating current and low-battery comparator in MSOP10
TPS60211	2-cell to regulated 3.3-V, 100-mA low-ripple charge pump with ultralow operating current and power-good comparator in MSOP10
TPS60212	2-cell to regulated 3.3-V, 100-mA low-ripple charge pump with ultralow operating current and low-battery comparator in MSOP10
TPS60213	2-cell to regulated 3.3-V, 50-mA low-ripple charge pump with ultralow operating current and power-good comparator in MSOP10

MECHANICAL DATA

DGS (S-DPS-G10)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES: A. All linear dimensions are in millimeters.
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion.

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